

5-V Low Drop Fixed Voltage Regulator

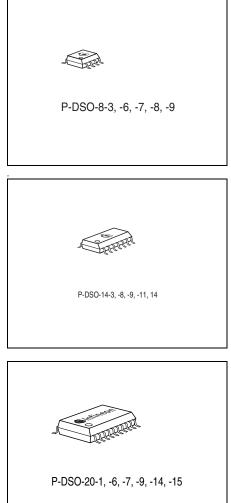
TLE 4269

Features

- Output voltage tolerance $\leq \pm 2\%$
- 150 mA current capability
- Very low current consumption
- Early warning
- Reset output low down to V_O = 1 V
- Overtemperature protection
- Reverse polarity proof
- Adjustable reset threshold
- Very low drop voltage
- Wide temperature range
- Integrated pull-up resistor at logic outputs

Functional Description

This device an automotive suited voltage regulator with a fixed 5-V output. The maximum operating voltage is 45 V. The output is able to drive 150 mA load. It is short circuit protected and the thermal shutdown switches the output off if the junction temperature is in excess of 150 °C. A reset signal is generated for an output voltage of $V_Q < 4.65$ V. The reset threshold voltage can be decreased by external connection of a voltage divider. The reset delay time can be set by an external capacitor. Reset and sense output have integrated pull-up resistors. If the integrated resistors are not desired **TLE 4279** can be used. It is also possible to supervise



the input voltage by using an integrated comparator to give a low voltage warning.

Туре	Ordering Code	Package		
TLE 4269 G	Q67006-A9173-A201K5	P-DSO-8-3		
TLE 4269 GM	Q67006-A9288-A201K5	P-DSO-14-8		
TLE 4269 GL	Q67006-A9192-C703	P-DSO-20-17		



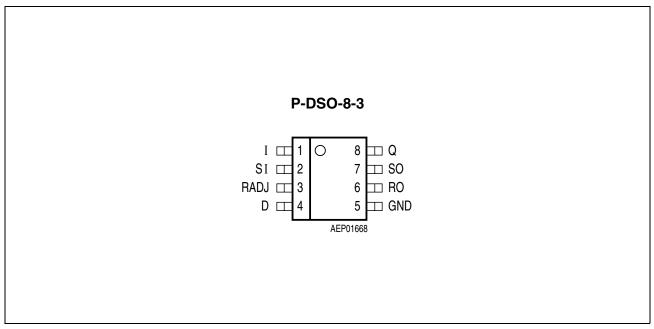


Figure 1 Pin Configuration (top view)

Table 1	le 1 Pin Definitions and Functions (TLE 4269 G)							
Pin No.	Symbol	Function						
1	I	Input; block to GND directly at the IC with a ceramic capacitor.						
2	SI	Sense Input; if not needed connect to Q.						
3	RADJ	Reset Threshold Adjust; if not needed connect to GND.						
4	D	Reset Delay; to select delay time, connect to GND via capacitor.						
5	GND	Ground						
6	RO	Reset Output; the open-collector output is internally linked to Q via a 20 k Ω pull-up resistor. Keep open, if not needed.						
7	SO	Sense Output; the open-collector output is internally linked to the output via a 20 k Ω pull-up resistor. Keep open, if not needed.						
8	Q	5-V Output; connect to GND with a 10 μ F capacitor, ESR < 10 Ω.						

۲/ = 1260 C)



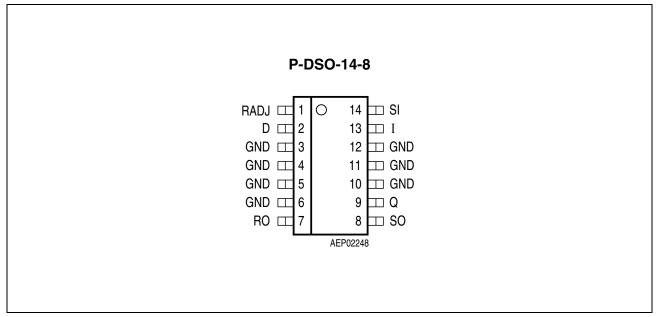


Figure 2 Pin Configuration (top view)

Table 2Pin Definitions and Functions (TLE 4269 GM)						
Pin No.	Symbol	Function				
1	RADJ	Reset Threshold Adjust; if not needed connect to GND.				
2	D	Reset Delay; to select delay time; connect to GND via capacitor.				
3, 4, 5, 6	GND	Ground				
7	RO	Reset Output; open-collector output, internally connected to Q via a pull-up resistor of 20 k Ω . Keep open, if not needed.				
8	SO	Sense Output; open-collector output, internally connected to Q via a 20 k Ω pull-up resistor. Keep open, if not needed.				
9	Q	5-V Output; connect to GND with a 10 μ F capacitor, ESR < 10 Ω.				
10, 11, 12	GND	Ground				
13	1	Input; block to GND directly at the IC with a ceramic capacitor.				
14	SI	Sense Input; if not needed connect to Q.				



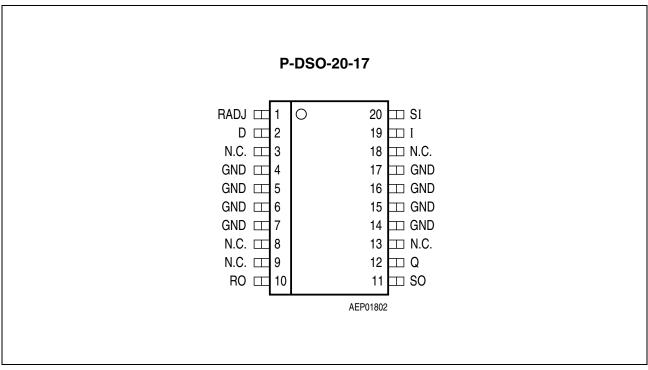


Figure 3Pin Configuration (top view)

Table 3Pin Definitions and Functions (TLE 4269 GL)

Pin No.	Symbol	Function
1	RADJ	Reset Threshold Adjust; if not needed connect to ground.
2	D	Reset Delay; to select delay time, connect to GND via external capacitor.
4 - 7, 14 - 17	GND	Ground
10	RO	Reset Output; the open-collector output is internally linked to Q via a 20 k Ω pull-up resistor. Keep open, if not needed.
11	SO	Sense Output; the open-collector output is internally linked to the output via a 20 k Ω pull-up resistor. Keep open, if not needed.
12	Q	Output; connect to GND with a 10 μ F capacitor, ESR < 10 Ω .
19	1	Input; block directly at the IC by a ceramic capacitor.
20	SI	Sense Input; if not needed connect to Q.



Circuit Description

The control amplifier compares a reference voltage, made highly accurate by resistance balancing, with a voltage proportional to the output voltage and drives the base of the series PNP transistor via a buffer. Saturation control as a function of the load current prevents any over-saturation of the power element.

The reset output RO is in high-state if the voltage on the delay capacitor $C_{\rm D}$ is greater or equal $V_{\rm UD}$. The delay capacitor $C_{\rm D}$ is charged with the current $I_{\rm D}$ for output voltages greater than the reset threshold $V_{\rm RT}$. If the output voltage gets lower than $V_{\rm RT}$ ('reset condition') a fast discharge of the delay capacitor $C_{\rm D}$ sets in and as soon as $V_{\rm D}$ gets lower than $V_{\rm LD}$ the reset output RO is set to low-level.

The time gap for the delay capacitor discharge is the reset reaction time t_{RR} .

The reset threshold V_{RT} can be decreased via an external voltage divider connected to the pin RADJ. In this case the reset condition is reached if $V_{\text{Q}} < V_{\text{RT}}$ and $V_{\text{RADJ}} < V_{\text{RAQDJ, TH}}$. Dimensioning the voltage divider (Figure 5) according to:

$$V_{\text{THRES}} = V_{\text{RADJ,TH}} \times (R_{\text{ADJ1}} + R_{\text{ADJ2}}) / R_{\text{ADJ2}}, \tag{1}$$

the reset threshold can be decreased down to 3.5 V. If the reset-adjust-option is not needed the RADJ-pin should be connected to GND causing the reset threshold to go to its default value (typ. 4.65 V).

A built in comparator compares the signal of the pin SI, normally fed by a voltage divider from the input voltage, with the reference and gives an early warning on the pin SO. It is also possible to superwise another voltage e.g. of a second regulator, or to build a watchdog circuit with few external components.

Application Description

The input capacitor $C_{\rm I}$ is necessary for compensating line influences. Using a resistor of approx. 1 Ω in series with $C_{\rm I}$, the oscillating circuit consisting of input inductivity and input capacitance can be damped. The output capacitor $C_{\rm Q}$ is necessary for the stability of the regulating circuit. Stability is guaranteed at values \geq 10 μ F and an ESR \leq 10 Ω within the operating temperature range. For small tolerances of the reset delay the spread of the capacitance of the delay capacitor and its temperature coefficient should be noted.



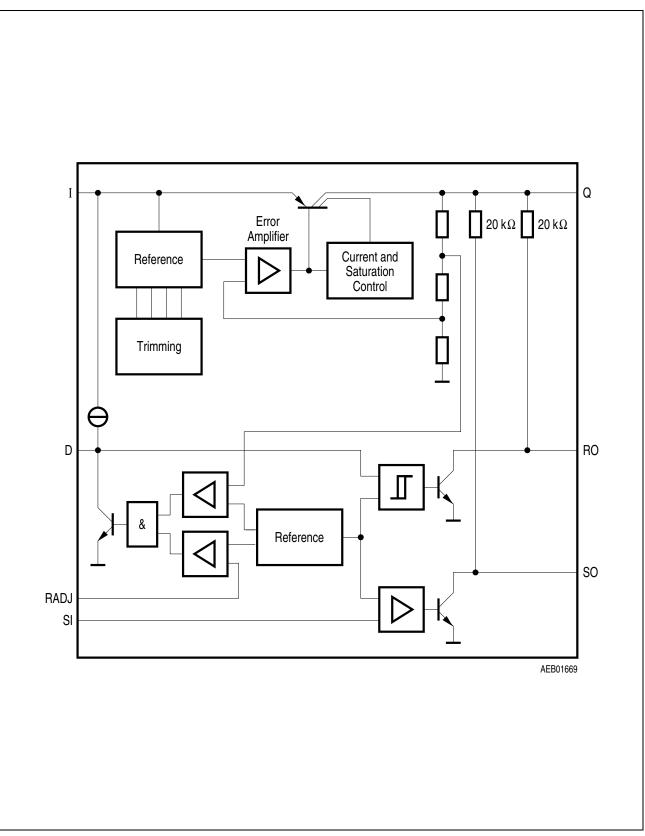


Figure 4 Block Diagram



Table 4 Absolute Maximum Ratings

 $T_{\rm j}$ = -40 to 150 °C

Parameter	Symbol	Limi	t Values	Unit	Notes
		Min.	Max.		
Input	- I	-	•		I
Input voltage	V_{I}	-40	45	V	-
Input current	I	-	-	-	internal limited
Sense Input	·	·	·		·
Input voltage	V _{SI}	-40	45	V	-
Input current	I _{SI}	1	1	mA	-
Reset Threshold	·	·	·		·
Voltage	V_{RADJ}	-0.3	7	V	-
Current	I _{RADJ}	-10	10	mA	-
Reset Delay					· ·
Voltage	V _D	-0.3	7	V	-
Current	ID	_	_	_	internal limited
Ground	·	·	·		·
Current	I _{GND}	50	-	mA	-
Reset Output	·	·	·		·
Voltage	V _R	-0.3	7	V	-
Current	I _R	-	_	_	internal limited
Sense Output	·	·	·		·
Voltage	V _{SO}	-0.3	7	V	-
Current	I _{SO}	-	-	-	internal limited
5-V Output					
Output voltage	V _Q	-0.5	7	V	-
Output current	IQ	-10	_	mA	-
Temperature					
Junction temperature	Tj	-	150	°C	-
Storage temperature	T _{Stg}	-50	150	°C	_



Table 4Absolute Maximum Ratings (cont'd)

 $T_{\rm j}$ = -40 to 150 °C

Parameter	Symbol	Limi	it Values	Unit	Notes
		Min.	Min. Max.		
Operating Range		•			
Input voltage	VI	-	45	V	_
Junction temperature	T _j	-40	150	°C	_
Thermal Data		•			
Junction-ambient	R _{thja}	- - -	200 70 70	K/W K/W K/W	P-DSO-8-3 P-DSO-14-8 P-DSO-20-17
Junction-pin	R _{thjp}		30 30	K/W K/W	P-DSO-14-8 ¹⁾ P-DSO-20-17 ¹⁾

1) Measured to Pin 4

Table 5Characteristics

 $V_{\rm I}$ = 13.5 V; $T_{\rm j}$ = -40 °C < $T_{\rm j}$ < 125 °C

Parameter	Symbol	Limit Values		Unit	Measuring	
		Min.	Тур.	Max.		Condition
Output voltage	V _Q	4.90	5.00	5.10	V	$1 \text{ mA} \le I_{\text{Q}} \le 100 \text{ mA}, \\ 6 \text{ V} \le V_{\text{I}} \le 16 \text{ V}$
Current limit	IQ	150	200	500	mA	-
Current consumption; $I_q = I_1 - I_Q$	Iq	-	240	300	μA	$I_{\rm Q} \le 1$ mA, $T_{\rm j} < 85 \ ^{\circ}{\rm C}$
$\overline{\text{Current consumption;}} \\ I_{q} = I_{l} - I_{Q}$	Iq	-	250	700	μA	<i>I</i> _Q = 10 mA
Current consumption; $I_q = I_1 - I_Q$	Iq	-	2	8	mA	$I_{\rm Q} = 50 \text{ mA}$
Drop voltage	V_{dr}	-	0.25	0.5	V	$I_{\rm Q} = 100 \ {\rm mA}^{1)}$
Load regulation	ΔV_{Q}	-	10	30	mV	$I_{\rm Q}$ = 5 mA to 100 mA
Line regulation	ΔV_{Q}	-	10	40	mV	$V_{\rm I}$ = 6 V to 26 V, $I_{\rm Q}$ = 1 mA



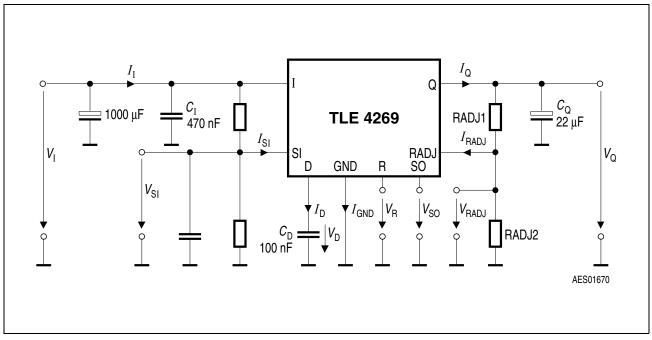
Table 5Characteristics (cont'd)

$V_{\rm I}$ = 13.5 V; $T_{\rm j}$ = -40 °C < $T_{\rm j}$ < 125 °C

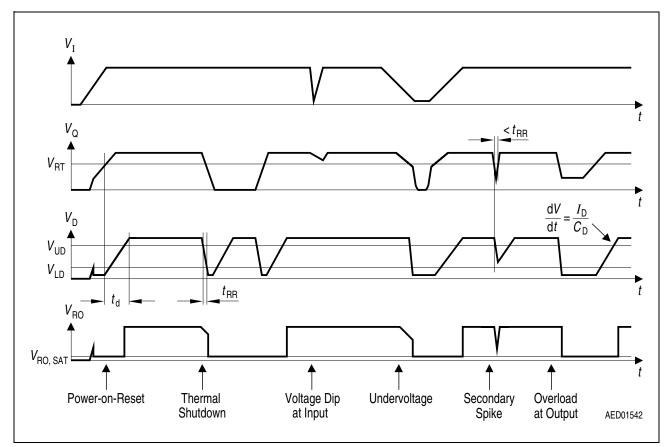
Parameter	Symbol	Limit Values			Unit	Measuring
		Min.	Тур.	Max.		Condition
Reset Generator						
Switching threshold	V_{RT}	4.50	4.65	4.80	V	-
Reset adjust switching threshold	$V_{RADJ, TH}$	1.26	1.35	1.44	V	V _Q > 3.5 V
Reset pull-up	-	10	20	40	kΩ	-
Saturation voltage	$V_{\mathrm{RO, SAT}}$	-	0.1	0.4	V	R _{intern}
Upper delay switching threshold	V _{UD}	1.4	1.8	2.2	V	-
Lower delay switching threshold	V _{LD}	0.3	0.45	0.60	V	-
Saturation voltage delay capacitor	$V_{D, SAT}$	-	-	0.1	V	$V_{\rm Q} < V_{\rm RT}$
Charge current	ID	3.0	6.5	9.5	μA	$V_{\rm D} = 1 \text{ V}$
Delay time $L \rightarrow H$	t _d	17	28	_	ms	C _D = 100 nF
Delay time $H \rightarrow L$	<i>t</i> t	-	1	-	μs	C _D = 100 nF
Input Voltage Sense						
Sense threshold high	$V_{ m SI,\ high}$	1.24	1.31	1.38	V	-
Sense threshold low	$V_{\rm SI, \ low}$	1.16	1.20	1.28	V	-
Sense output low voltage	$V_{ m SO,\ low}$	_	0.1	0.4	V	$V_{\rm SI}$ < 1.20 V; $V_{\rm Q}$ > 3 V, $R_{\rm intern}$
Sense pull-up	-	10	20	40	kΩ	-
Sense input current	I _{SI}	-1	0.1	1	μA	-

1) Drop voltage = $V_1 - V_Q$ measured when the output voltage has dropped 100 mV from the nominal value obtained at 13.5 V input.













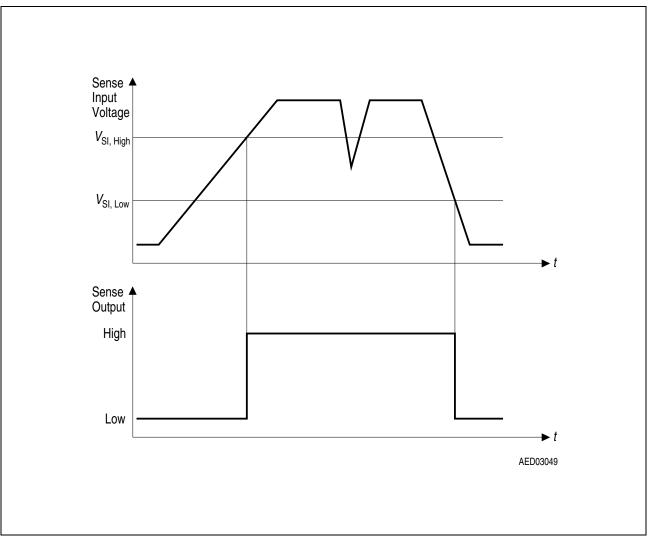
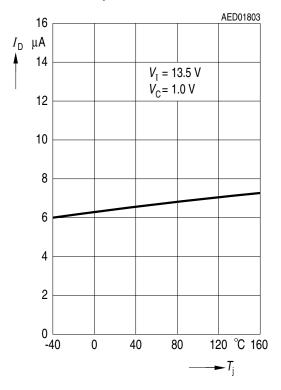


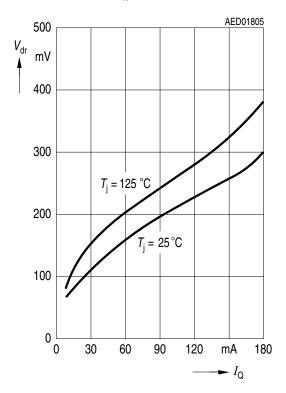
Figure 7 Sense Timing Diagram



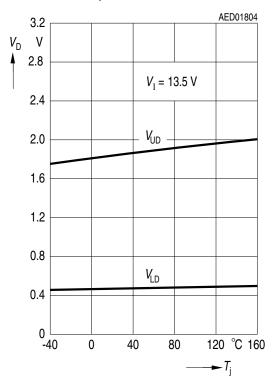
Charge Current $I_{\rm D}$ versus Temperature $T_{\rm i}$



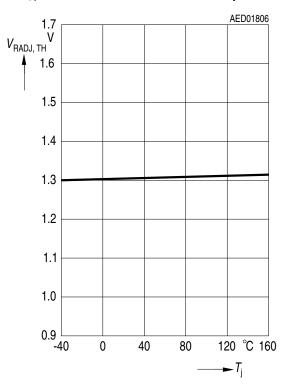
Drop Voltage $V_{\rm dr}$ versus Output Current $I_{\rm Q}$

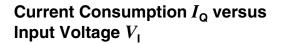


Switching Voltage $V_{\rm UD}$ and $V_{\rm LD}$ versus Temperature $T_{\rm i}$

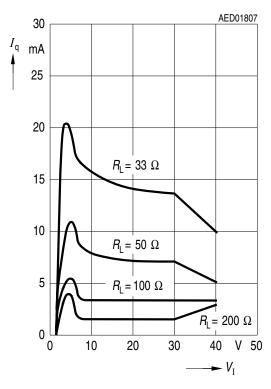


Reset Adjust Switching Threshold $V_{\text{RADJ,TH}}$ versus Temperature T_{i}

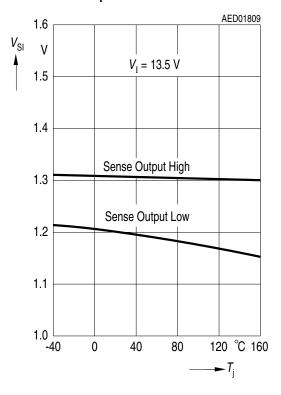




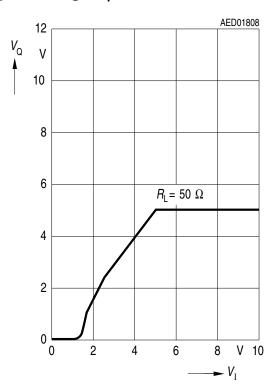
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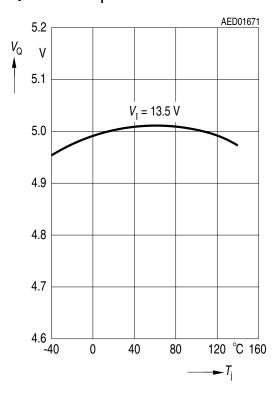
Sense Threshold V_{SI} versus Temperature T_i



Output Voltage $V_{\rm Q}$ versus Input Voltage $V_{\rm I}$

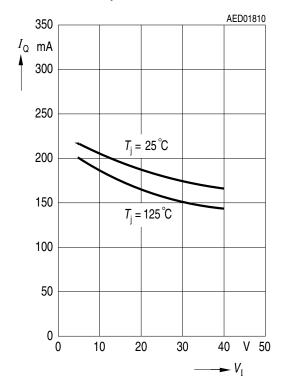


Output Voltage V_{Q} versus Temperature T_{i}

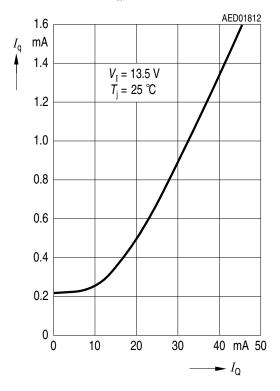




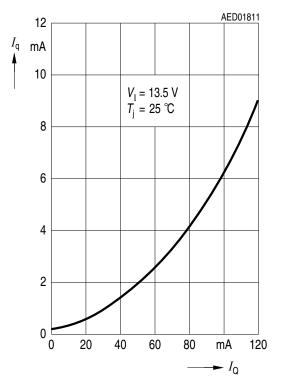
Output Current $I_{\rm Q}$ versus Input Voltage $V_{\rm I}$



Current Consumption I_q versus Output Current I_Q



Current Consumption I_q versus Output Current I_q





Package Outlines

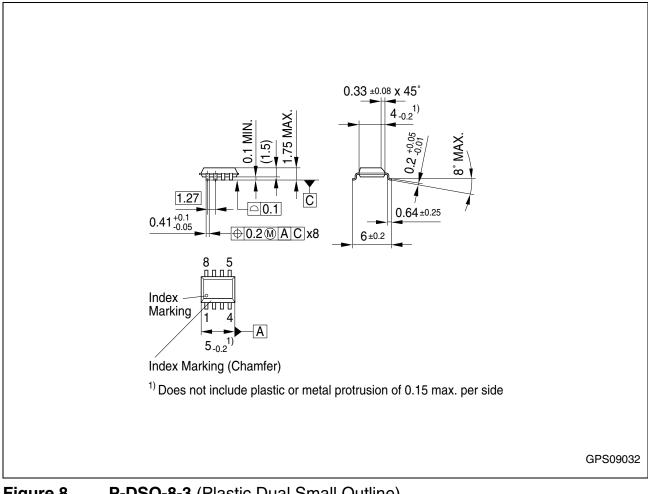


Figure 8 P-DSO-8-3 (Plastic Dual Small Outline)

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SMD = Surface Mounted Device

Dimensions in mm



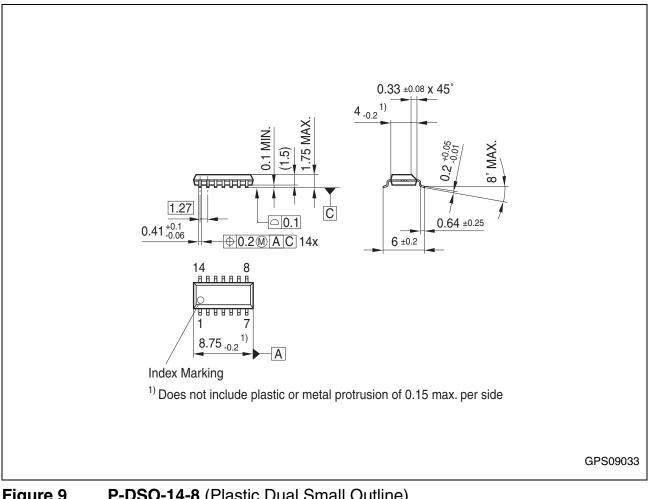


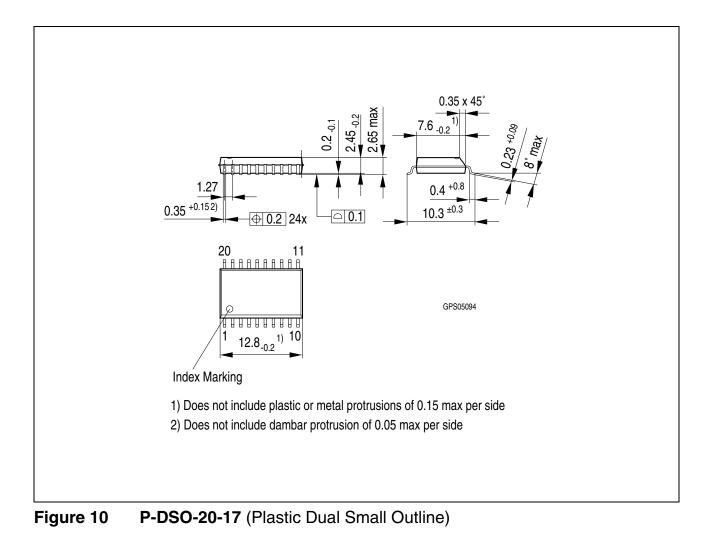
Figure 9 P-DSO-14-8 (Plastic Dual Small Outline)

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Dimensions in mm





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